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#### FEATURES

- CDMA/EVDO, WCDMA/HSPA and LTE Compliant
- 3<sup>rd</sup> Generation HELP<sup>™</sup> technology
- High Efficiency: (LTE waveform)
  - 35 % @ Pout = +27.25 dBm
  - 20 % @ Pout = +16 dBm
- Simpler Calibration with only 2 Bias Modes
- Optimized for SMPS Supply
- Low Quiescent Current: 8mA
- Low Leakage Current in Shutdown Mode: 4 μA
- Internal Voltage Regulator
- Integrated "daisy chainable" directional couplers with CPLIN and CPLOUT Ports
- Optimized for a 50  $\Omega$  System
- Low Profile Miniature Surface Mount Package
- Internal DC blocks on IN/OUT RF ports
- 1.8 V Control Logic
- RoHS Compliant Package, 260 °C MSL-3

# APPLICATIONS

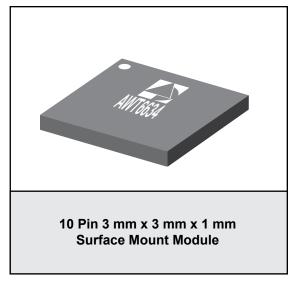
- Wireless Handsets and Data Devices for:
  - WCDMA/HSPA/LTE Bands 3,4,9 or 10
  - CDMA/EVDO AWS/KPCS Band

# **PRODUCT DESCRIPTION**

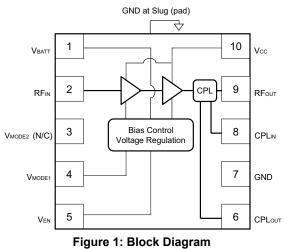
The AWT6634 PA is designed to provide highly linear output for WCDMA, CDMA and LTE handsets and data devices with high efficiency at both high and low power modes. This HELP3DC<sup>™</sup> PA can be used with an external switch mode power supply (SMPS) to improve its effciency and reduce current consumption further at medium and low output powers. A "daisy chainable" directional coupler is integrated in the module thus eliminating the need of external couplers. The device is manufactured on an advanced InGaP HBT MMIC technology offering state-of-the-art reliability, temperature stability, and ruggedness. There

# HELP3DC<sup>™</sup> UMTS1700 (Band 4 & 9) LTE/WCDMA/CDMA Linear PA Module DATA SHEET - Rev 2.1

**AWT6634** 



are two selectable bias modes that optimize efficiency for different output power levels, and a shutdown mode with low leakage current, which increases handset talk and standby time. The self-contained 3 mm x 3 mm x1 mm surface mount package incorporates matching networks optimized for output power, efficiency, and linearity in a 50  $\Omega$  system.



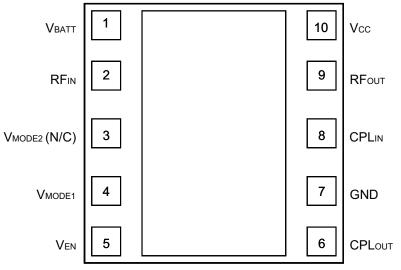


Figure 2: Pinout (X-ray Top View)

PIN	NAME	DESCRIPTION
1	VBATT	Battery Voltage
2	RFℕ	RF Input
3	VMODE2 (N/C)	No Connection
4	VMODE1	Mode Control Voltage 1
5	Ven	PA Enable Voltage
6	CPLout	Coupler Output
7	GND	Ground
8	CPLℕ	Coupler Input
9	RFout	RF Output
10	Vcc	Supply Voltage

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# **ELECTRICAL CHARACTERISTICS**

Table 2. Absolute Minimum and Maximum Ratings								
PARAMETER	MIN	MAX	UNIT					
Supply Voltage (Vcc)	0	+5	V					
Battery Voltage (VBATT)	0	+6	V					
Control Voltages (VMODE1, VENABLE)	0	+3.5	V					
RF Input Power (Pℕ)	-	+10	dBm					
Storage Temperature (T <sub>STG</sub> )	-40	+150	°C					

 Table 2: Absolute Minimum and Maximum Ratings

Stresses in excess of the absolute ratings may cause permanent damage. Functional operation is not implied under these conditions. Exposure to absolute ratings for extended periods of time may adversely affect reliability.

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
Operating Frequency (f)	1710	-	1785	MHz	
Supply Voltage (Vcc)	+0.5	+3.4	+4.35	V	Pouт ≤ +28.25 dBm
Battery Voltage (VBATT)	+3.1	+3.4	+4.35	V	Pouт ≤ +28.25 dBm
Enable Voltage (Venable)	+1.35 0	+1.8 0	+3.1 +0.5	V	PA "on" PA "shut down"
Mode Control Voltage (V <sub>MODE1</sub> )	+1.35 0	+1.8 0	+3.1 +0.5	V	Low Bias Mode High Bias Mode
RF Output Power (Ρουτ) R99 WCDMA, HPM HSPA (MPR=0), HPM LTE, HPM R99 WCDMA, LPM HSPA (MPR=0), LPM LTE, LPM	$27.45^{(1)} \\ 26.45^{(1)} \\ 26.45^{(1)} \\ 16.2^{(1)} \\ 15.2^{(1)} \\ $	28.25 27.25 27.25 17 16 16	28.25 27.25 27.25 17 16 16	dBm	3GPP TS 34.121-1, Rel 8 Table C.11.1.3 for WCDMA SUBTEST 1 TS 36.101 Rel 8 LTE
CDMA Output Power HPM LPM	26.7 <sup>(1)</sup> 15.2 <sup>(1)</sup>	27.5 16.0	-	dBm	CDMA2000, RC-1
Case Temperature (Tc)	-30	-	+90	°C	

Table 3: Operating Ranges

The device may be operated safely over these conditions; however, parametric performance is guaranteed only over the conditions defined in the electrical specifications.

Notes:

(1) For operation at Vcc = +3.1 V, Pout is derated by 0.8 dB.

Table 4: Electrical Specifications - WCDMA Operation (R99 waveform)	
(T <sub>c</sub> = +25 °C, V <sub>cc</sub> = +3.4 V, V <sub>BATT</sub> = +3.4 V, V <sub>ENABLE</sub> = +1.8 V, 50 $\Omega$ system)	

(1c = +25 °C, Vcc =					COMMENTS		
PARAMETER	MIN	TYP	MAX	UNIT	Ρουτ	VMODE1	
Gain	24.5 11.5	27 14	29.5 16	dB	+28.25 dBm +17 dBm	0 V 1.8 V	
ACLR1 at 5 MHz offset (1)	-	-41 -41	-38 -38	dBc	+28.25 dBm +17 dBm	0 V 1.8 V	
ACLR2 at 10 MHz offset	-	-55 -60	-48 -53	dBc	+28.25 dBm +17 dBm	0 V 1.8 V	
Power-Added Efficiency (1)	37 20	40 23	-	%	+28.25 dBm +17 dBm	0 V 1.8 V	
Quiescent Current (Icq) Low Bias Mode	-	8	16.5	mA	V <sub>MODE1</sub> = +1.8 V		
Mode Control Current	-	0.3	0.6	mA	through VMODE pir	n, Vmode1 = +1.8 V	
Enable Current	-	0.3	0.6	mA	through Venable p	pin	
BATT Current	-	2.5	5	mA	through VBATT, VM	10DE1 = +1.8V	
Leakage Current	-	4	7	μA	VBATT = +4.2 V, V <sub>CC</sub> = +4.2 V, VENABLE = 0 V, VMODE1 = 0 V		
Noise in Receive Band	-	-134 -141 -134	- -	dBm/Hz	1805 - 1880 MHz 2110 - 2155 MHz 1574.4 - 1576.4 MHz		
Harmonics 2fo 3fo, 4fo	-	-37 -55	-34 -50	dBc	Pouт <u>≤</u> +28.25 dB	3m	
Input Impedance	-	2:1	-	VSWR			
Coupling Factor	-	20	-	dB			
Directivity	-	28	-	dB			
Coupler IN-OUT Daisy Chain Insertion Loss	-	0.25	-	dB	698 MHz through 2620 MHz Pin 8 to 6; Shutdown Mode		
Spurious Output Level (all spurious outputs)	-	-	-70	dBc	Pout $\leq$ +28.25 dBm In-band load VSWR < 5:1 Out-of-band load VSWR < 10:1 Applies over all operating conditions		
Load mismatch stress with no permanent degradation or failure	8:1	-	-	VSWR	Applies over full operating range		
Phase Delta (HPM-LPM)	-	10	-	Deg			

Notes:

(1) ACLR and Efficiency measured at 1747.5 MHz.

Table 5: Electrical Specifications - LTE Operation (RB = 12, START = 0, QPSK)
(Tc = +25 °C, VBATT = Vcc = +3.4 V, VENABLE = +1.8 V, 50 $\Omega$ system)

PARAMETER	MINI	ТҮР	MAY	UNIT	COMMENTS		
PARAMETER	MIN	ITP	MAX	וואט	Ролт	V <sub>MODE1</sub>	
Gain	24.5 11.5	27 14	29.5 16	dB	+27.25 dBm +16 dBm	0 V 1.8 V	
ACLR E-UTRA at ± 10 MHz offset	-	-39 -39	-36 -36	dBc	+27.25 dBm +16 dBm	0 V 1.8 V	
ACLR1 UTRA <sup>(1)</sup> at ± 7.5 MHz offset	-	-40 -40	-37 -37	dBc	+27.25 dBm +16 dBm	0 V 1.8 V	
ACLR2 UTRA at ± 12.5 MHz offset	-	-60 -60	-55 -55	dBc	+27.25 dBm +16 dBm	0 V 1.8 V	
Power-Added Efficiency (1)	32 16	35 20		%	+27.25 dBm +16 dBm	0 V 1.8 V	
Spurious Output Level (all spurious outputs)	-	-	<-70	dBc	Pout ≤ +27.25 dBm In-band load VSWR < 5:1 Out-of-band load VSWR < 10:1 Applies over all operating condition		
Load mismatch stress with no permanent degradation or failure	8:1	-	-	VSWR	Applies over full operating range		

Notes:

(1) ACLR and Efficiency measured at 1747.5 MHz.

		TVD	MAY		COMMENTS	
PARAMETER	MIN	TYP	MAX	UNIT	Роит	VMODE1
Gain	24.5 11.5	27 14	29.5 16	dB	+27.5 dBm +16 dBm	0 V 1.8 V
Adjacent Channel Power at +1.25 MHz offset Primary Channel BW = 1.23 MHz Adjacent Channel BW = 30 kHz	-	-50 -50	-46 -46	dBc	+27.5 dBm +16 dBm	0 V 1.8 V
Adjacent Channel Power at +1.98 MHz offset Primary Channel BW = 1.23 MHz Adjacent Channel BW = 30 kHz		-55 -60	-51 -56	dBc	+27.5 dBm +16 dBm	0 V 1.8 V
Power-Added Efficiency	- -	36 20	- -	%	+27.5 dBm +16 dBm	0 V 1.8 V
Spurious Output Level (all spurious outputs)	-	-	-70	dBc	See Note 1	
Load mismatch stress with no permanent degradation or failure	8:1	-	-	VSWR	Applies over full operating range	

Table 6: Electrical Specifications - CDMA Operation (CDMA 2000 RC1 WAVEFORM) $(T_c = +25 \ ^{\circ}C, V_{cc} = V_{BATT} = +3.4 \ V, V_{ENABLE} = +1.8 \ V, 50 \ \Omega \ system)$ 

Notes:

(1) ACPR and Efficiency measured at 1747.5 MHz.

# APPLICATION INFORMATION

To ensure proper performance, refer to all related Application Notes on the ANADIGICS web site: http://www.anadigics.com

#### Shutdown Mode

The power amplifier may be placed in a shutdown mode by applying logic low levels (see Operating Ranges table) to the VENABLE and VMODE1 voltages.

#### **Bias Modes**

The power amplifier may be placed in either a Low Bias mode or a High Bias mode by applying the appropriate

logic level (see Operating Ranges table) to  $V_{MODE1}$ . The Bias Control table lists the recommended modes of operation for various applications.  $V_{MODE2}$  is not necessary for this PA.

Two operating modes are available to optimize current consumption. High Bias/High Power operating mode is for  $P_{OUT}$  levels  $\geq$  16 dBm. At around 16 dBm output power, the PA should be "Mode Switched" to Low power mode for lowest quiescent current consumption.

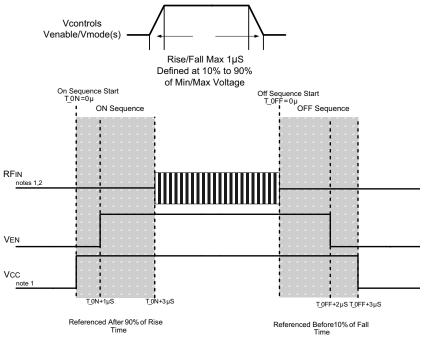


Figure 3: Recommended ON/OFF Timing Sequence

Notes:

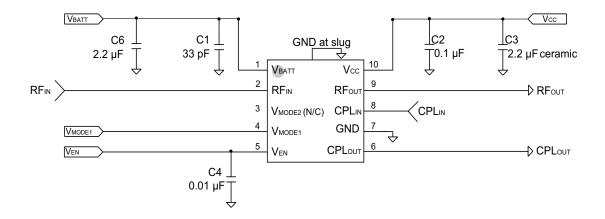
(1) Level might be changed after RF is ON.

(2) RF OFF defined as  $P_{IN} \leq -30 \text{ dBm}$ .

(3) Switching simultaneously between VMODE and VEN is not recommended.

Table 7: Bias Control

Application	Pout LEVELS	BIAS MODE	VENABLE	VMODE1	Vcc	VBATT
High power (High Bias Mode)	>+16 dBm	High	+1.8 V	0 V	1.5 - 4.35 V	> 3.1 V
Med/low power (Low Bias Mode)	≤ +17 dBm	Low	+1.8 V	+1.8 V	0.5 - 4.35 V	> 3.1 V
Shutdown	-	Shutdown	0 V	0 V	0.5 - 4.35 V	> 3.1 V





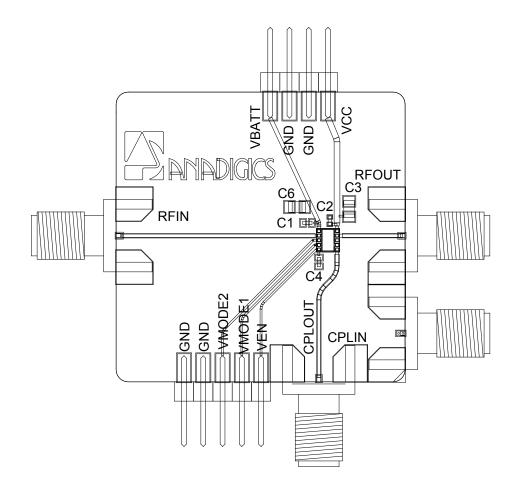


Figure 5: Evaluation Board Layout

#### HELP3DC<sup>™</sup>

The AWT6634 power amplifier module is based on ANADIGICS proprietary HELP3DC<sup>™</sup> technology. The PA is designed to operate up to 17 dBm in the low power mode, thus eliminating the need for three gain states, while still maintaining low quiescent current and high efficiency in low and medium power levels. Average weighted efficiency can be increased by using an external switch mode power supply (SMPS) or DC/DC converter to reduce Vcc.

The directional "daisy chainable" coupler is integrated within the PA module, therefore there is no need for external couplers. The AWT6634 has an integrated voltage regulator, which eliminates the need for an external constant voltage source. The PA is turn on/off is controlled by VEN pin. A single VMODE control logic (VMODE1) is needed to operate this device. AWT6634 requires only two calibration sweeps for system calibration, thus saving calibration time.

Figure 5 shows one application example on mobile board. C1 and C2 are RF bypass caps and should be placed nearby pin 1 and pin 10. Bypass caps C4 and C5 may not be needed. Also a "T" matching topology is recommended at PA RFIN and RFOUT ports to provide matching between input TX Filter and Duplexer / Isolator.

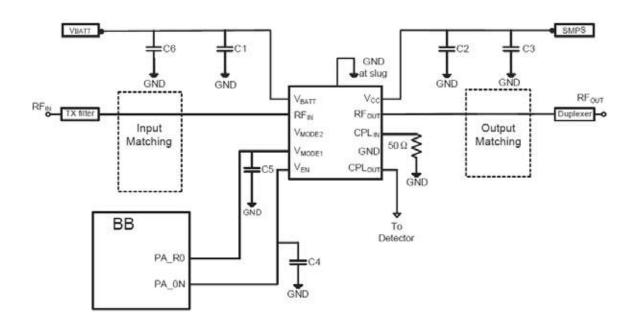
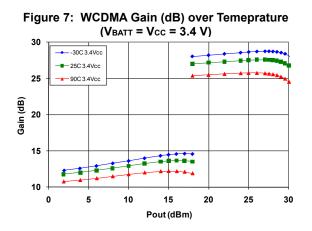


Figure 6: Typical Application Circuit

#### **PERFORMANCE DATA:**



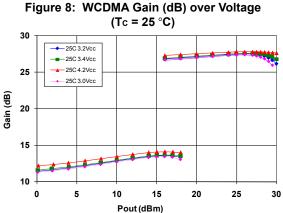
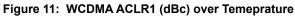


Figure 9: WCDMA PAE (%) over Temeprature  $(V_{BATT} = V_{CC} = 3.4 V)$ 50 -30 3.4cc - 25C 3.4Vcc 40 90C 3.4Vcc Efficiency (%) 30 20 10 0 0 5 10 15 20 25 30 Pout (dBm)



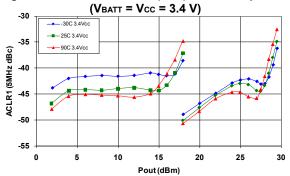
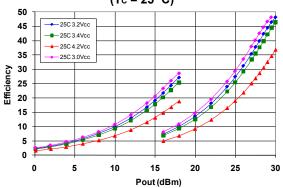
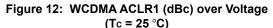
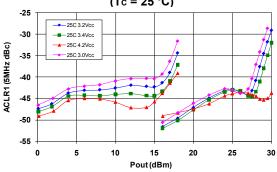


Figure 10: WCDMA PAE (%) over Voltage (Tc =  $25 \degree$ C)



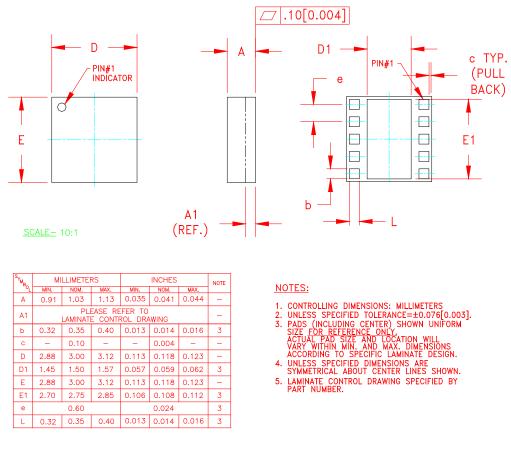




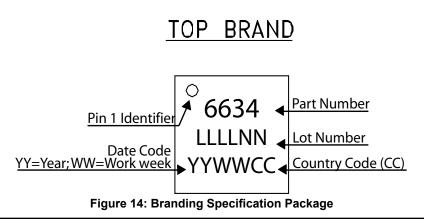
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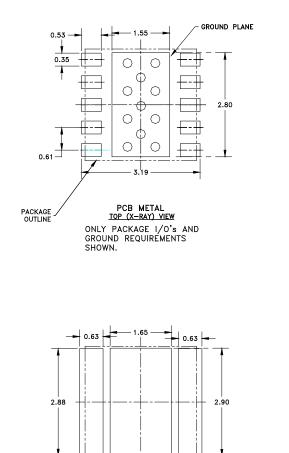
# PACKAGE OUTLINE







# PCB AND STENCIL DESIGN GUIDELINE



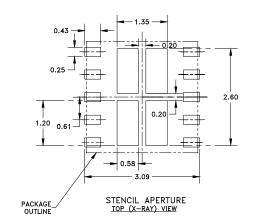
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PCB SOLDER MASK

TOP (X-RAY) VIEW

NOTES:

- (1) OUTLINE DRAWING REFERENCE: P8002478\_E
- (2) UNLESS SPECIFIED DIMENSIONS ARE SYMMETRICAL ABOUT CENTER LINES SHOWN.
- (3) DIMENSIONS IN MILLIMETERS.
- (4) VIAS SHOWN IN PCB METAL VIEW ARE FOR REFERENCE ONLY. NUMBER & SIZE OF THERMAL VIAS REQUIRED DEPENDENT ON HEAT DISSIPATION REQUIREMENT AND THE PCB PROCESS CAPABILITY.
- (5) RECOMMENDED STENCIL THICKNESS: APPROX. 0.150mm (6 Mils)



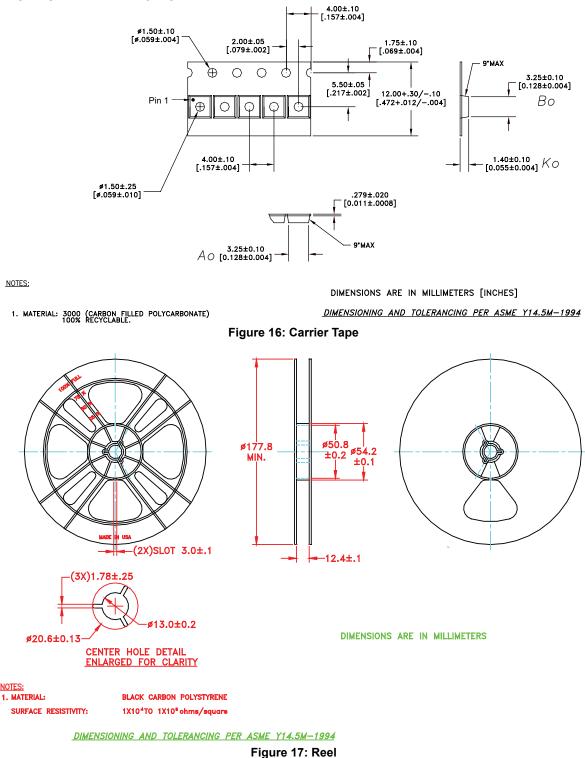


PACKAGE

OUTLINE

NOTES:

#### **COMPONENT PACKAGING**



NOTES:

#### **ORDERING INFORMATION**

ORDER NUMBER	TEMPERATURE RANGE	PACKAGE DESCRIPTION	COMPONENT PACKAGING
AWT6634Q7	-30 °C to +90 °C	RoHS Compliant 10 Pin 3 mm x 3 mm x 1 mm Surface Mount Module	Tape and Reel, 2500 pieces per Reel
AWT6634P9	-30 °C to +90 °C	RoHS Compliant 10 Pin 3 mm x 3 mm x 1 mm Surface Mount Module	Partial Tape and Reel

# **ANADIGICS**

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